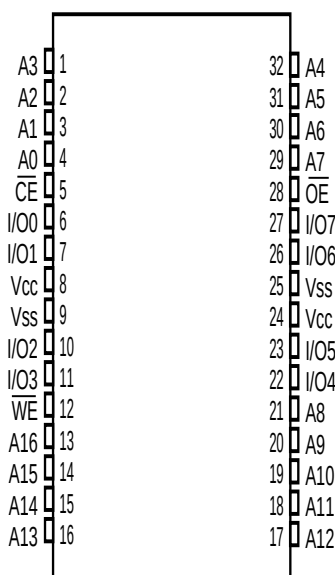


Pin Configuration

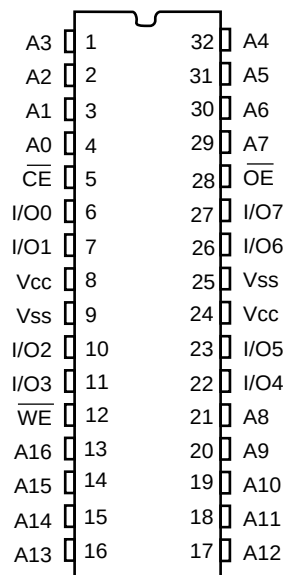
Pin Description

Name	Description
A16-A0	Address Inputs
I/O7-I/O0	Data Inputs/Outputs
$\overline{OE}$	Output Enable Input
$\overline{WE}$	Write Enable Input
$\overline{CE}$	Chip Enable Input
NC	No Connect
V _{CC}	Power (+3.3V)
V _{SS}	Ground

TSOP



SOJ

Truth Table⁽¹⁾

$\overline{CE}$	$\overline{OE}$	$\overline{WE}$	I/O	MODE
L	L	H	D _{OUT}	Read
L	X	L	D _{IN}	Write
L	H	H	Hi-Z	Output Disable
H	X	X	Hi-Z	Standby

NOTE: 1. H = V_{IH}, L = V_{IL}, X = DON'T CARE

Absolute Maximum Ratings⁽¹⁾

Symbol	Rating	Com'l.	Ind.	Auto.	Unit
V _{TERM}	Terminal Voltage with Respect to V _{SS}	-0.5 to +4.6	-0.5 to +4.6	-0.5 to +4.6	V
T _{BIAS}	Temperature Under Bias	-55 to +125	-65 to +135	-65 to +145	°C
T _{STG}	Storage Temperature	-55 to +125	-65 to +150	-65 to +150	°C
P _T	Power Dissipation	900	900	900	mW
I _{OUT}	DC Output Current	50	50	50	mA
T _j	Maximum Junction Temperature ⁽²⁾	125	125	125	°C

- NOTE: 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. Appropriate thermal calculations should be performed in all cases and specifically for those where the chosen package has a large thermal resistance (e.g., TSOP). The calculation should be of the form: $T_j = T_a + P * \theta_{ja}$ where T_a is the ambient temperature, P is average operating power and θ_{ja} the thermal resistance of the package. For this product, use the following θ_{ja} values:

SOJ: 72° C/W

TSOP: 95° C/W

Recommended DC Operating Conditions

Symbol	Parameter	Min.	Typ.	Max.	Unit
V _{CC}	Supply Voltage	3.0	3.3	3.6	V
V _{SS}	Supply Voltage	0	0	0	V
Industrial	Ambient Temperature	−40	25	85	°C
Commercial	Ambient Temperature	−0	25	70	°C

DC Electrical Characteristics (V_{CC} = 3.3V ± 0.3V)

Symbol	Parameter	Test Conditions		Min.	Max.	Unit
I _{LI}	Input Leakage Current	V _{CC} = Max., V _{IN} = V _{SS} to V _{CC}	Com'l/ Ind.	−5	5	μA
I _{LO}	Output Leakage Current	V _{CC} = Max., CE = V _{IH} , V _{OUT} = V _{SS} to V _{CC}	Com'l/ Ind.	−5	5	μA
V _{IL}	Input Low Voltage			−0.3 ⁽¹⁾	0.8	V
V _{IH}	Input High Voltage			2.2	V _{CC} +0.3	V
V _{OL}	Output Low Voltage	I _{OL} = 8 mA, V _{CC} = Min.		—	0.4	V
V _{OH}	Output High Voltage	I _{OH} = −4 mA, V _{CC} = Min.		2.4	—	V

NOTE:1.V_{IL}(min) = −3.0V for pulse width less than 20 ns**Power Supply Characteristics**

Symbol	Parameter	−9 ⁽¹⁾	−10 ⁽¹⁾	−12		−15			−20			Unit
		Com'l.	Com'l.	Com'l.	Ind.	Com'l.	Ind.	Auto.	Com'l.	Ind.	Auto.	
I _{CC}	Operating Current CE = V _{IL} f = f _{MAX} = 1/t _{RC} V _{CC} = Max. I _{OUT} = 0 mA	125	115	110	115	100	105	110	90	95	110	mA
I _{SB}	Standby Current CE = V _{IH} f = f _{MAX} = 1/t _{RC} V _{CC} = Max.	20	20	20	20	20	20	30	20	20	30	mA
I _{SB1}	Full Standby Current CE ≥ V _{CC} − 0.2V f = 0 V _{CC} = Max., V _{IN} ≥ V _{CC} − 0.2V or ≤ 0.2V	5	5	5	5	5	5	10	5	5	10	mA

NOTES: All values are maximum guaranteed values.

1. V_{CC} = 3.3V ± 5%

Capacitance⁽¹⁾ ($T_A = +25^\circ\text{C}$, $f = 1.0\text{ MHz}$)

Symbol	Parameter	Max.	Unit
C_{IN}	Input Capacitance	8	pF
C_{OUT}	Output Capacitance	8	pF

NOTE:1. This parameter is determined by device characterization but is not production tested.

AC Test Conditions

Input pulse levels	V_{SS} to 3.0V
Input rise and fall times	2.5 ns
Input timing reference levels	1.5V
Output reference levels	1.5V
Output load	See Figures 1 and 2

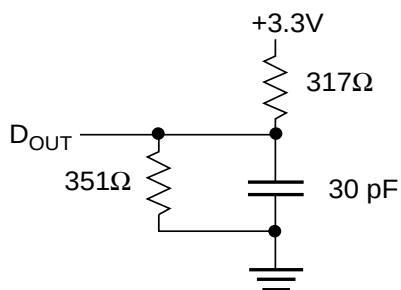


Figure 1. Output Load Equivalent

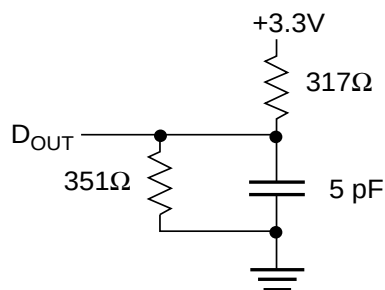
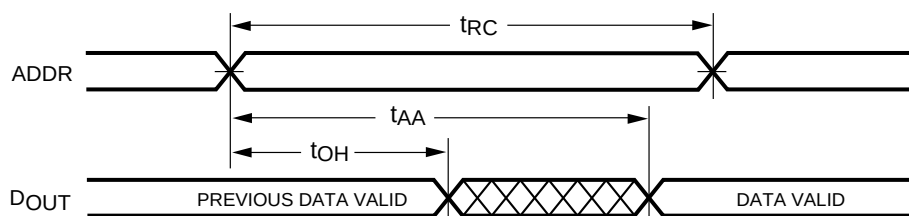
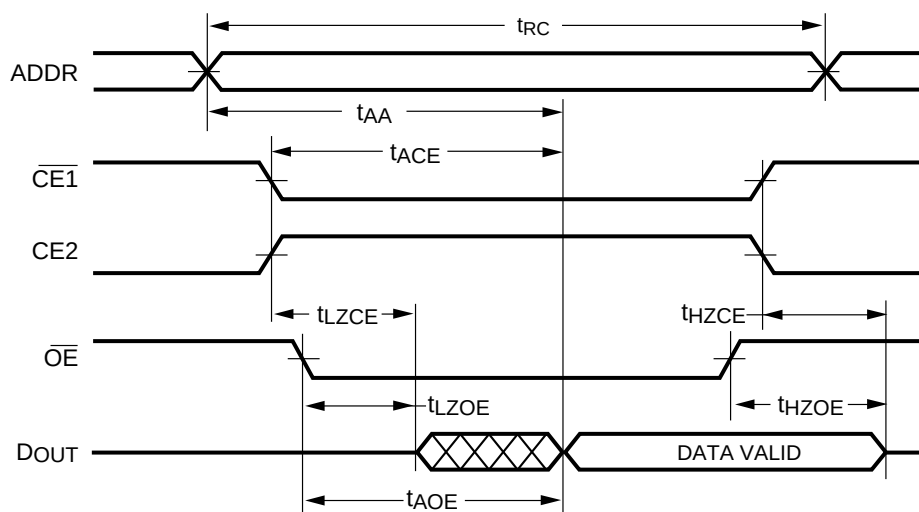
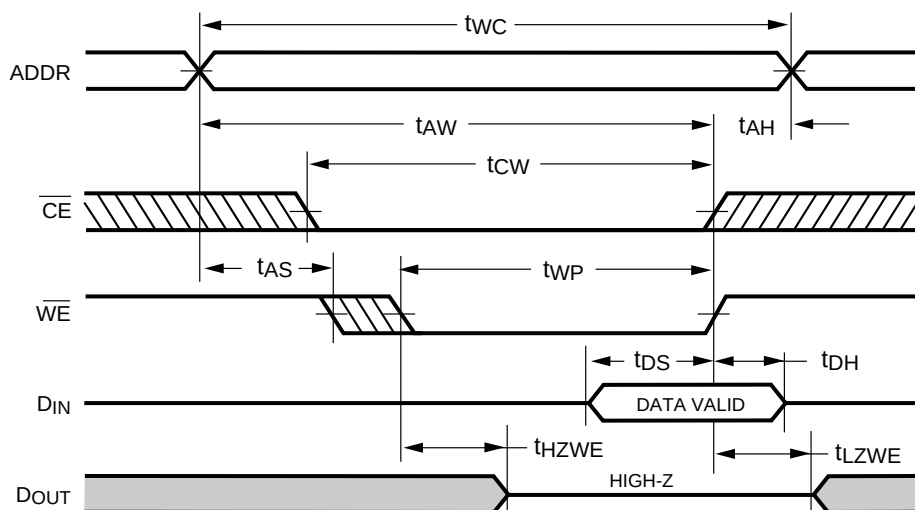


Figure 2. Output Load Equivalent
(for t_{LZCE} , t_{HZCE} , t_{LZWE} , t_{HZWE} , t_{LZOE} ,
 t_{HZOE})

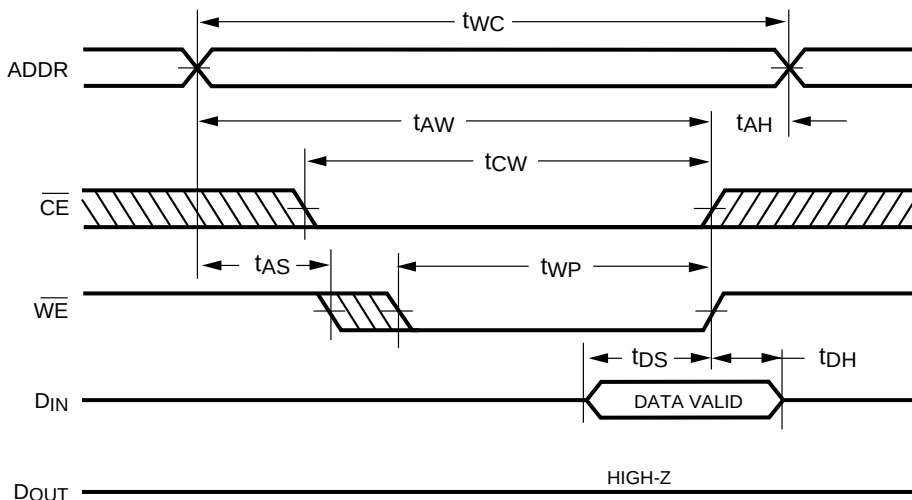
Read Cycle No. 1^(4, 5)**Read Cycle No. 2^(2, 4, 6)****AC Electrical Characteristics**

Description	Sym	-9		-10		-12		-15		-20		Units
READ Cycle		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
READ cycle time	t_{RC}	9		10		12		15		20		ns
Address access time	t_{AA}		9		10		12		15		20	ns
Chip enable access time	t_{ACE}		9		10		12		15		20	ns
Output hold from address change	t_{OH}	3		3		3		3		3		ns
Chip enable to output in low Z ^(1,3)	t_{LZCE}	3		3		3		3		3		ns
Chip disable to output in high Z ^(1,2,3)	t_{HZCE}		5		6		7		8		9	ns
Chip enable to power up time ⁽³⁾	t_{PU}	0		0		0		0		0		ns
Chip disable to power down time ⁽³⁾	t_{PD}		9		10		12		15		20	ns
Output enable access time	t_{AOE}		5		6		7		8		9	ns
Output Enable to output in low Z ^(1,3)	t_{LZOE}	0		0		0		0		0		ns
Output disable to output in high Z ^(1,3)	t_{HZOE}		5		6		7		8		9	ns

Write Cycle No. 1 (Write Enable Controlled)

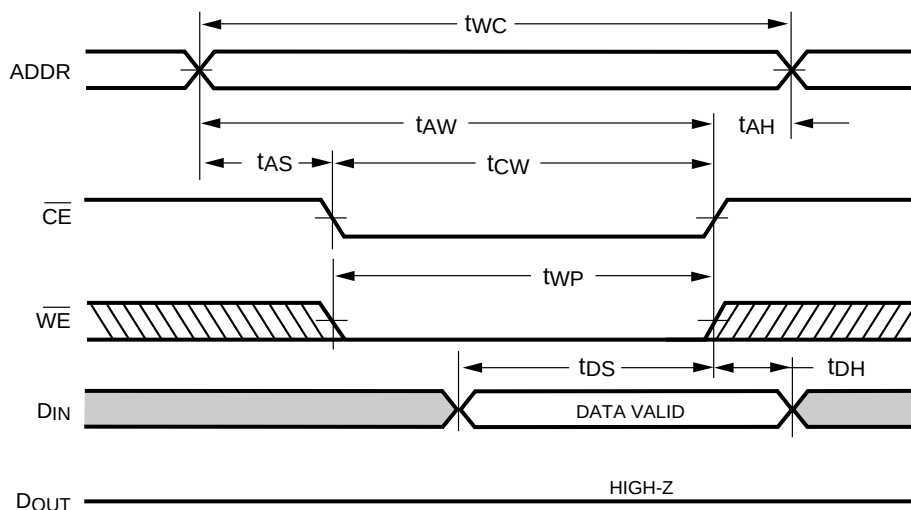


Write Cycle No. 2 (Write Enable Controlled)



NOTE: Output Enable ($\overline{OE}$) is inactive (high)

Write Cycle No. 3 (Chip Enable Controlled)



NOTE: Output Enable ($\overline{OE}$) is inactive (high)

AC Electrical Characteristics

Description		-9		-10		-12		-15		-20		
WRITE Cycle	Sym	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
WRITE cycle time	t_{WC}	9		10		12		15		20		ns
Chip enable active time	t_{CW}	8		9		10		11		12		ns
Address valid to end of write	t_{AW}	8		9		10		11		12		ns
Address setup time	t_{AS}	0		0		0		0		0		ns
Address hold from end of write	t_{AH}	0		0		0		0		0		ns
Write pulse width	t_{WP}	7		8		9		10		11		ns
Data setup time	t_{DS}	5		6		7		8		9		ns
Data hold time	t_{DH}	0		0		0		0		0		ns
Write disable to output in low $Z^{(1,3)}$	t_{LZWE}	0		0		0		0		0		ns
Write enable to output in high $Z^{(1,3)}$	t_{HZWE}		6		7		7		8		9	ns

NOTES: (For two previous Electrical Characteristics tables)

1. The parameter is tested with $C_L = 5$ pF as shown in Figure 2. Transition is measured ± 200 mV from steady state voltage.
2. At any given temperature and voltage condition, t_{HZCE} is less than t_{LZCE} .
3. This parameter is sampled.
4. $\overline{WE}$ is high for a READ cycle.
5. The device is continuously selected. Chip Enable is held in their active state.
6. The address is valid prior to or coincident with the latest occurring Chip Enable.

Ordering Information

XXXXX Device Type	X Power	XX Speed	X Package Type	X Process Temp. Range	X Preferred Shipping Container	
						Blank Tubes
						TR Tape & Reel
						TY Tray
						Blank Commercial (0° to +70°C)
						I Industrial (–40°C to +85°C)
						A Automotive (–40°C to +105°C)
						SO 32-pin 400 mil Plastic SOJ
						TSO 32-pin 300 mil Plastic SOJ
						T 32-pin Plastic TSOP (II)
						9 Commercial Only
						10
						12
						15
						20
						SA Standard Power
						PDM31034 - (128Kx8) Static RAM